

<b>SANYO</b>	No.1069C	<b>2SC3150</b>
NPN Triple Diffused Planar Silicon Transistor <b>FOR SWITCHING REGULATOR</b>		

**Features**

- . High breakdown voltage ( $V_{CBO} \geq 900V$ )
- . High speed switching.
- . Wide ASO.

**Absolute Maximum Ratings at  $T_a=25^\circ C$**

			unit
Collector-to-Base Voltage	$V_{CBO}$	900	V
Collector-to-Emitter Voltage	$V_{CEO}$	800	V
Emitter-to-Base Voltage	$V_{EBO}$	7	V
Collector Current	$I_C$	3	A
Peak Collector Current	$i_{cp}$	$PW \leq 300\mu s,$ Duty Cycle $\leq 10\%$	10 A
Base Current	$I_B$	1.5	A
Collector Dissipation	$P_C$	$T_C=25^\circ C$	50 W
Junction Temperature	$T_j$	150	$^\circ C$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ C$

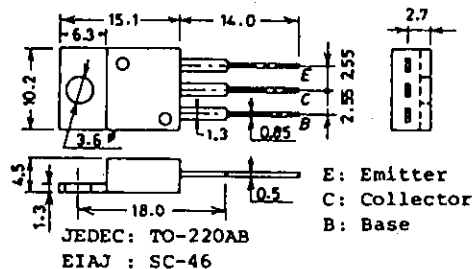
**Electrical Characteristics at  $T_a=25^\circ C$**

			min	typ	max	unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=800V, I_E=0$			10	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=5V, I_C=0$			10	$\mu A$
DC Current Gain	$h_{FE}(1)$	$V_{CE}=5V, I_C=0.2A$	10*		40*	
	$h_{FE}(2)$	$V_{CE}=5V, I_C=1A$	8			
Gain-Bandwidth Product	$f_T$	$V_{CE}=10V, I_C=0.2A$		15		MHz
Output Capacitance	$c_{ob}$	$V_{CB}=10V, f=1MHz$		60		pF
C-E Saturation Voltage	$V_{CE}(sat)$	$I_C=1.5A, I_B=0.3A$			2.0	V
B-E Saturation Voltage	$V_{BE}(sat)$	$I_C=1.5A, I_B=0.3A$			1.5	V
C-B Breakdown Voltage	$V(BR)_{CBO}$	$I_C=1mA, I_E=0$	900			V
C-E Breakdown Voltage	$V(BR)_{CEO}$	$I_C=5mA, R_{BE}=\infty$	800			V
E-B Breakdown Voltage	$V(BR)_{EBO}$	$I_E=1mA, I_C=0$	7			V
C-E Sustain Voltage	$V_{CEO}(sus)$	$I_C=3A, L=500\mu H, I_B=1A$	800			V
	$V_{CEX}(sus)(1)$	$I_C=1A, I_{B1}=0.2A, I_{B2}=-0.2A, L=2mH, clamped$	800			V
	$V_{CEX}(sus)(2)$	$I_C=0.5A, I_{B1}=0.1A, I_{B2}=-0.1A, L=5mH, clamped$	900			V
Turn-ON Time	$t_{on}$	$\left[ \begin{array}{l} I_C=2A, I_{B1}=0.4A, I_{B2}=-0.8A, \\ R_L=200ohms, V_{CC}=400V \end{array} \right]$			1.0	$\mu s$
Storage Time	$t_{stg}$				3.0	$\mu s$
Fall Time	$t_f$				0.7	$\mu s$

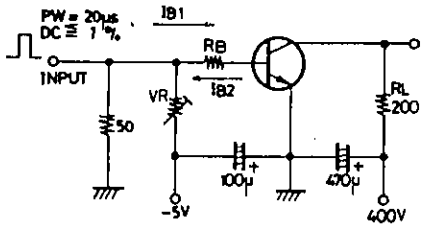
\*: The  $h_{FE}(1)$  of the 2SC3150 is classified as follows. When specifying the  $h_{FE}(1)$  rank, specify two ranks or more in principle.

10	K	20	15	L	30	20	M	40
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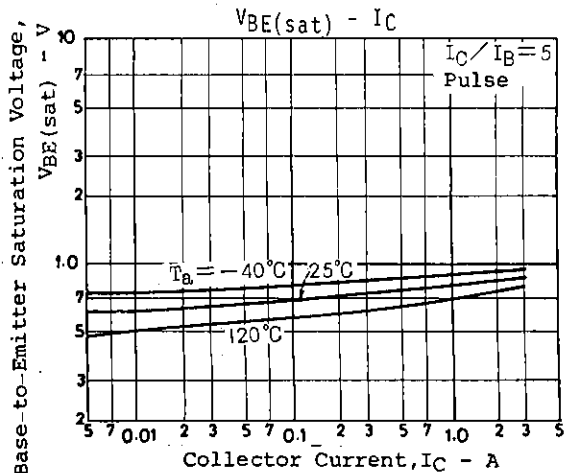
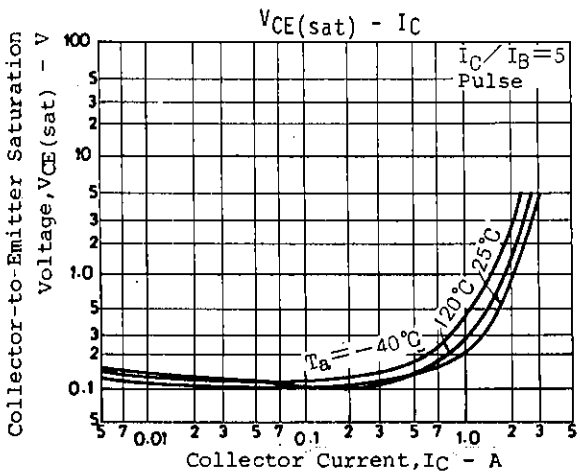
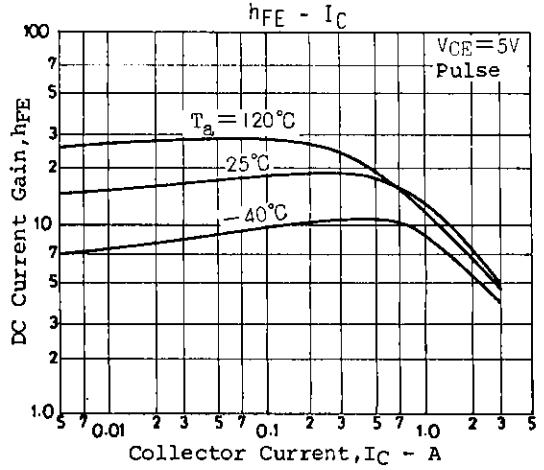
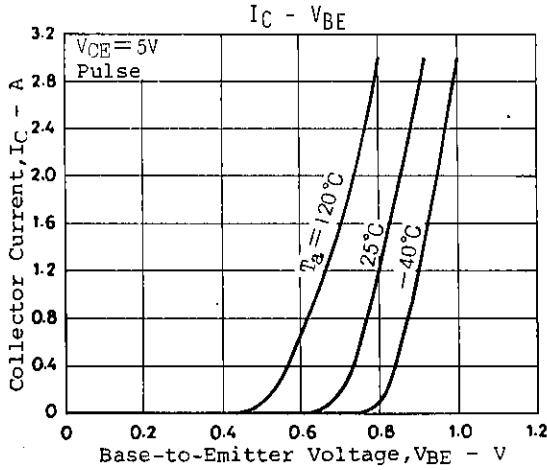
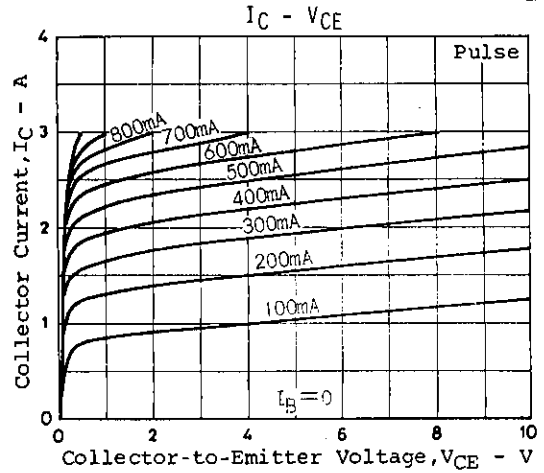
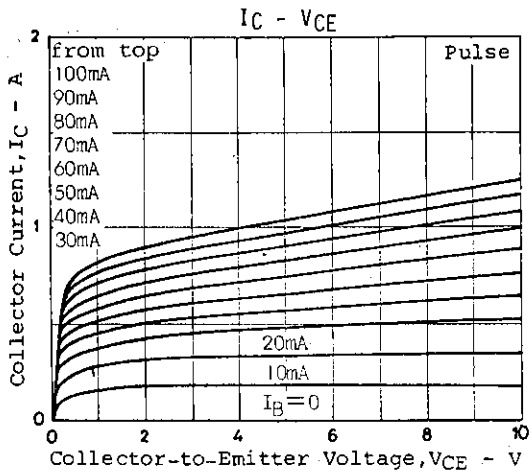
**Package Dimensions 2010A (unit:mm)**

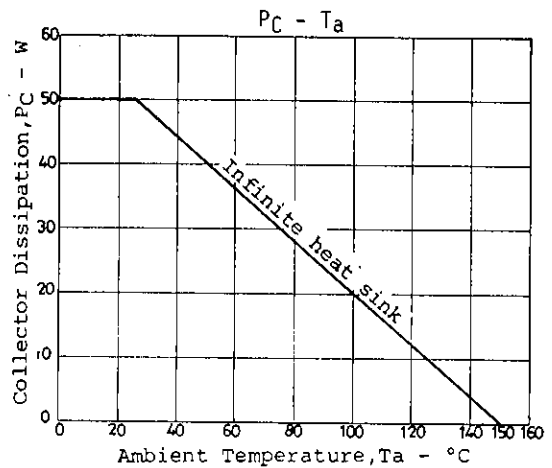
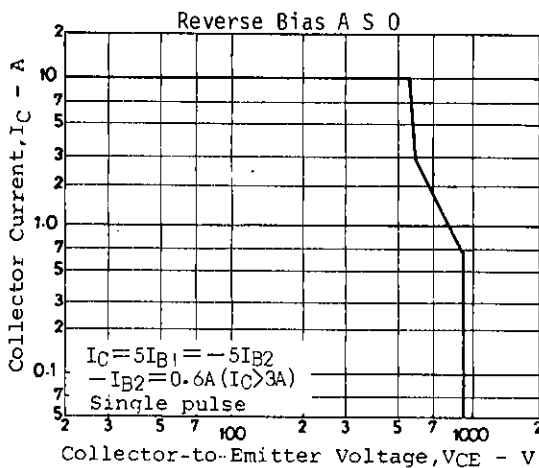
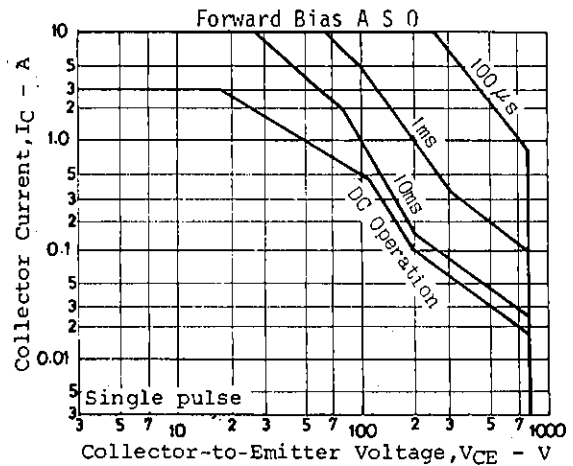
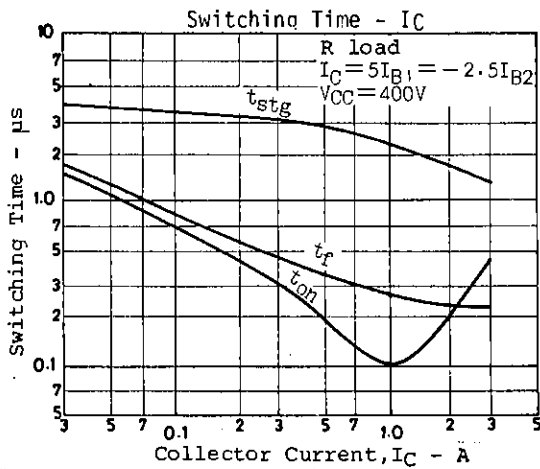


Switching Time Test Circuit



Unit (Resistance : Ω, Capacitance : F)





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